

# MPSA14\_D75Z Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number MPSA14\_D75Z-DG

Manufacturer onsemi

Manufacturer Product Number MPSA14\_D75Z

Description TRANS NPN DARL 30V 1.2A TO92-3

Detailed Description Bipolar (BJT) Transistor NPN - Darlington 30 V 1.2 A

125MHz 625 mW Through Hole TO-92-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



MPSA14

# **Purchase and inquiry**

| Manufacturer Product Number:                 | Manufacturer:                          |
|----------------------------------------------|----------------------------------------|
| MPSA14_D75Z                                  | onsemi                                 |
| Series:                                      | Product Status:                        |
|                                              | Obsolete                               |
| Transistor Type:                             | Current - Collector (Ic) (Max):        |
| NPN - Darlington                             | 1.2 A                                  |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, Ic:         |
| 30 V                                         | 1.5V @ 100μA, 100mA                    |
| Current - Collector Cutoff (Max):            | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| 100nA (ICBO)                                 | 20000 @ 100mA, 5V                      |
| Power - Max:                                 | Frequency - Transition:                |
| 625 mW                                       | 125MHz                                 |
| Operating Temperature:                       | Mounting Type:                         |
| -55°C ~ 150°C (TJ)                           | Through Hole                           |
| Package / Case:                              | Supplier Device Package:               |
| TO-226-3, TO-92-3 (TO-226AA) Formed Leads    | TO-92-3                                |
| Base Product Number:                         |                                        |

# **Environmental & Export classification**

| Moisture Sensitivity Level (MSL): | REACH Status:    |
|-----------------------------------|------------------|
| 1 (Unlimited)                     | REACH Unaffected |
| ECCN:                             | HTSUS:           |
| FAR99                             | 8541 21 0075     |



#### Is Now Part of



# ON Semiconductor®

# To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to Fairchild <a href="guestions@onsemi.com">guestions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products for any particular purpose, nor does ON Semiconductor assume any liability to make changes without further notice to any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expense

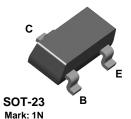


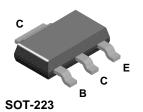
#### MPSA14

#### MMBTA14

### PZTA14







## **NPN Darlington Transistor**

This device is designed for applications requiring extremely high current gain at collector currents to 1.0 A. Sourced from Process 05.

#### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

| Symbol                            | Parameter                                        | Value       | Units |
|-----------------------------------|--------------------------------------------------|-------------|-------|
| V <sub>CES</sub>                  | Collector-Emitter Voltage                        | 30          | V     |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 30          | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 10          | V     |
| Ic                                | Collector Current - Continuous                   | 1.2         | А     |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.

  2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### **Thermal Characteristics**

TA = 25°C unless otherwise noted

| Symbol          | Characteristic Max                         |            |            |              |             |  |  |  |
|-----------------|--------------------------------------------|------------|------------|--------------|-------------|--|--|--|
|                 |                                            | MPSA14     | *MMBTA14   | **PZTA14     |             |  |  |  |
| $P_D$           | Total Device Dissipation Derate above 25°C | 625<br>5.0 | 350<br>2.8 | 1,000<br>8.0 | mW<br>mW/°C |  |  |  |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case       | 83.3       |            |              | °C/W        |  |  |  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient    | 200        | 357        | 125          | °C/W        |  |  |  |

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

<sup>\*\*</sup>Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

#### **NPN Darlington Transistor**

(continued)

| _ |        |         |     | $\sim$ |      |     | -   | 4 *  |
|---|--------|---------|-----|--------|------|-----|-----|------|
|   | $\sim$ | + r 1 / | 221 | ľ'n    | ara  | ヘナハ | ric | +100 |
|   | ᇆ      |         | Jai | C I    | ıaıa | CLE |     | LIGS |

TA = 25°C unless otherwise noted

| Symbol               | Parameter                           | Test Conditions                    | Min | Max | Units |
|----------------------|-------------------------------------|------------------------------------|-----|-----|-------|
| OFF CHAI             | RACTERISTICS                        |                                    |     |     |       |
| V <sub>(BR)CES</sub> | Collector-Emitter Breakdown Voltage | $I_C = 100  \mu A,  I_B = 0$       | 30  |     | V     |
| I <sub>CBO</sub>     | Collector-Cutoff Current            |                                    | 100 | nA  |       |
| I <sub>EBO</sub>     | Emitter-Cutoff Current              | $V_{EB} = 10 \text{ V}, I_{C} = 0$ |     | 100 | nA    |

#### ON CHARACTERISTICS\*

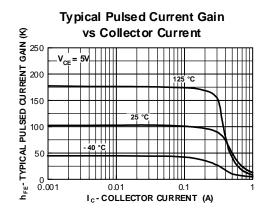
| h <sub>FE</sub>      | DC Current Gain                      | $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$<br>$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$ | 10,000<br>20,000 |     |   |
|----------------------|--------------------------------------|-------------------------------------------------------------------------------------------------|------------------|-----|---|
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | $I_C = 100 \text{ mA}, I_B = 0.1 \text{ mA}$                                                    |                  | 1.5 | V |
| V <sub>BE(on)</sub>  | Base-Emitter On Voltage              | $I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$                                                  |                  | 2.0 | V |

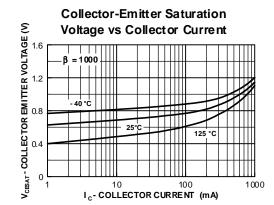
#### SMALL SIGNAL CHARACTERISTICS

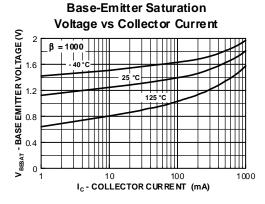
| f⊤ | Current Gain - Bandwidth Product | $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V},$ | 125 | MHz |
|----|----------------------------------|----------------------------------------------|-----|-----|
|    |                                  | f = 100 MHz                                  |     |     |

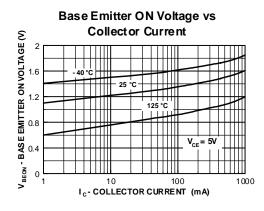
<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

#### **Typical Characteristics**





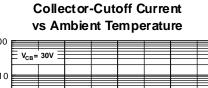


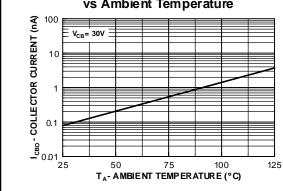


#### **NPN Darlington Transistor**

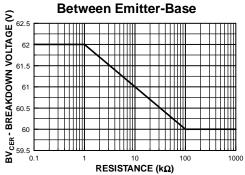
(continued)

#### Typical Characteristics (continued)

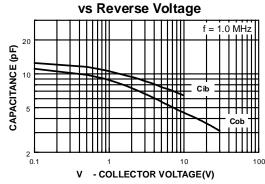




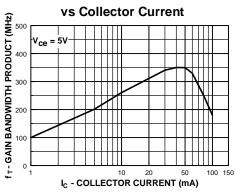
# **Collector-Emitter Breakdown** Voltage with Resistance



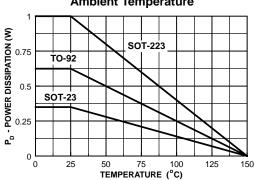
## **Input and Output Capacitance**

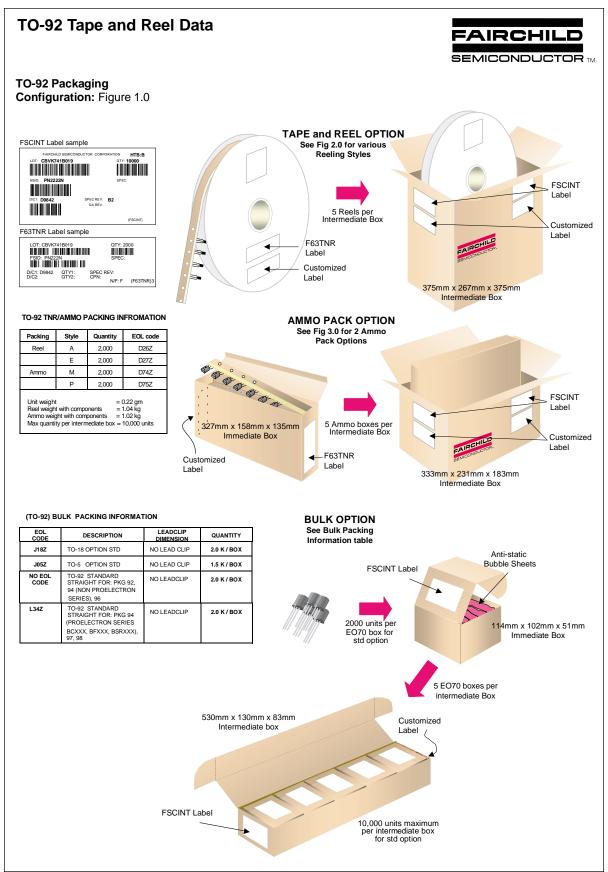


# **Gain Bandwidth Product**



#### **Power Dissipation vs Ambient Temperature**

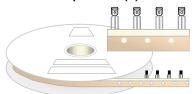




#### TO-92 Tape and Reel Data, continued

#### **TO-92 Reeling Style** Configuration: Figure 2.0

#### Machine Option "A" (H)



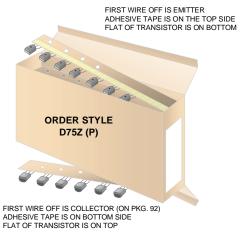
Style "A", D26Z, D70Z (s/h)

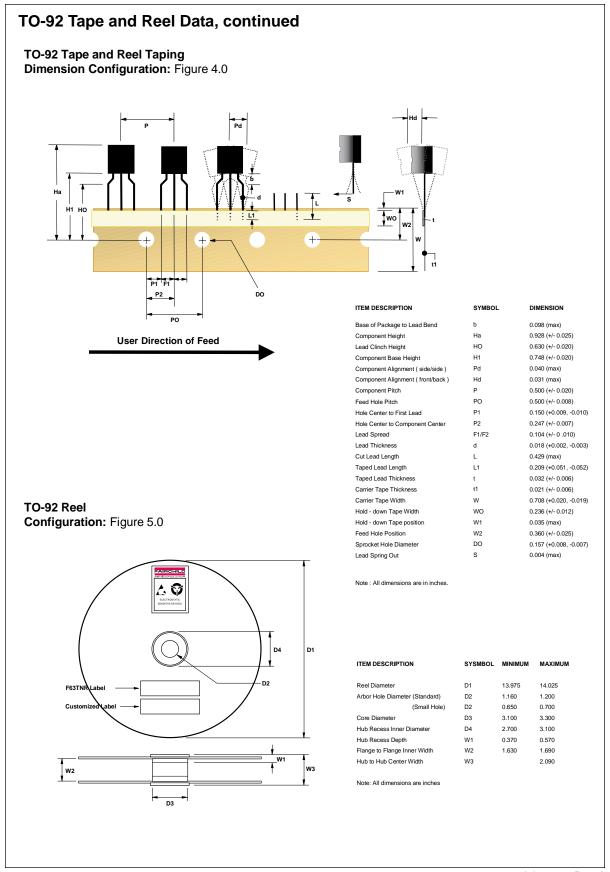
# Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

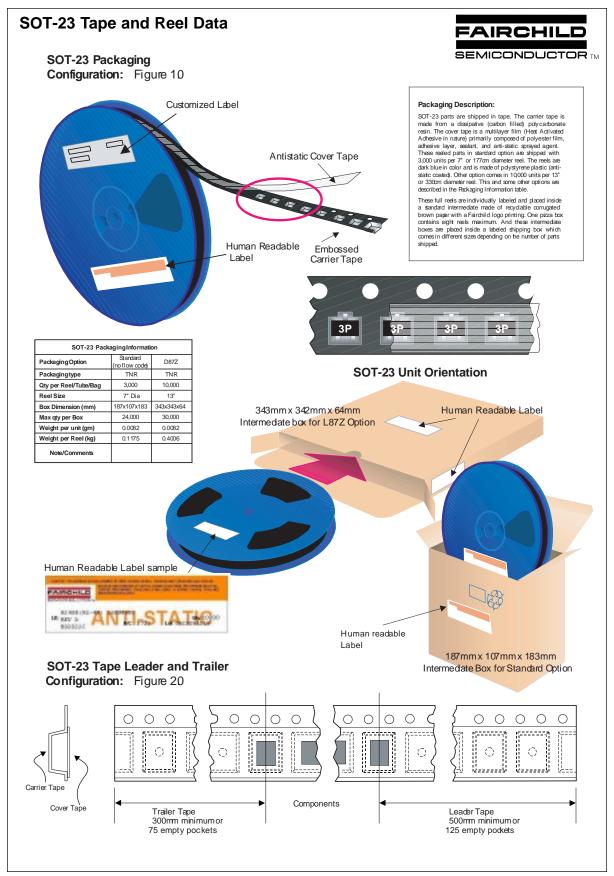
#### **TO-92 Radial Ammo Packaging** Configuration: Figure 3.0







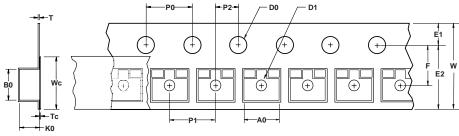
# **TO-92 Package Dimensions** SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 В В B F В D 2 В S С G Ε D Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.



#### SOT-23 Tape and Reel Data, continued

#### **SOT-23 Embossed Carrier Tape**

Configuration: Figure 3.0



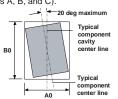
| User Direction of Feed |  |
|------------------------|--|
|                        |  |
|                        |  |

|                     | Dimensions are in millimeter                                                                                                                                    |                 |               |                 |                   |                 |             |                 |               |               |                 |                   |               |                 |
|---------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|---------------|-----------------|-------------------|-----------------|-------------|-----------------|---------------|---------------|-----------------|-------------------|---------------|-----------------|
| Pkg type            | Pkg type         A0         B0         W         D0         D1         E1         E2         F         P1         P0         K0         T         Wc         Tc |                 |               |                 |                   |                 |             |                 |               |               |                 |                   |               |                 |
| <b>SOT-23</b> (8mm) | 3.15<br>+/-0.10                                                                                                                                                 | 2.77<br>+/-0.10 | 8.0<br>+/-0.3 | 1.55<br>+/-0.05 | 1.125<br>+/-0.125 | 1.75<br>+/-0.10 | 6.25<br>min | 3.50<br>+/-0.05 | 4.0<br>+/-0.1 | 4.0<br>+/-0.1 | 1.30<br>+/-0.10 | 0.228<br>+/-0.013 | 5.2<br>+/-0.3 | 0.06<br>+/-0.02 |

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



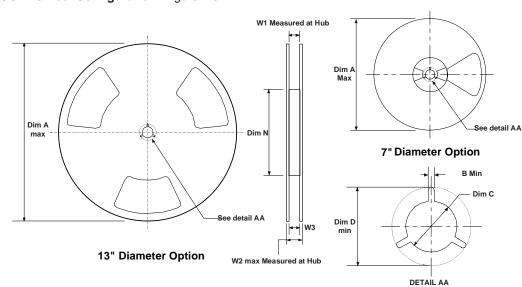
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

#### SOT-23 Reel Configuration: Figure 4.0

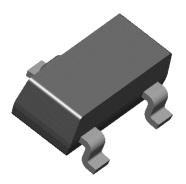


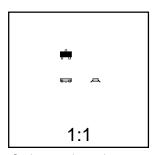
|                                                                               | Dimensions are in inches and millimeters |               |              |                                   |               |             |                                   |               |                             |  |  |
|-------------------------------------------------------------------------------|------------------------------------------|---------------|--------------|-----------------------------------|---------------|-------------|-----------------------------------|---------------|-----------------------------|--|--|
| Tape Size Reel Option Dim A Dim B Dim C Dim D Dim N Dim W1 Dim W2 Dim W3 (LSL |                                          |               |              |                                   |               |             | Dim W3 (LSL-USL)                  |               |                             |  |  |
| 8mm                                                                           | 7" Dia                                   | 7.00<br>177.8 | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 2.165<br>55 | 0.331 +0.059/-0.000<br>8.4 +1.5/0 | 0.567<br>14.4 | 0.311 - 0.429<br>7.9 - 10.9 |  |  |
| 8mm                                                                           | 13" Dia                                  | 13.00<br>330  | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 4.00<br>100 | 0.331 +0.059/-0.000<br>8.4 +1.5/0 | 0.567<br>14.4 | 0.311 - 0.429<br>7.9 - 10.9 |  |  |

#### **SOT-23 Package Dimensions**



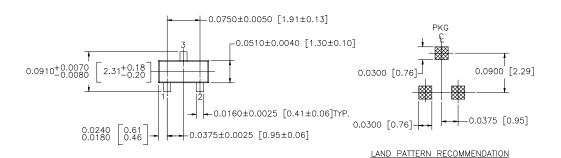
# SOT-23 (FS PKG Code 49)

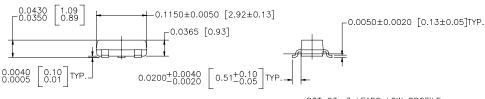




Scale 1:1 on letter size paper Dimensions shown below are in:

inches [millimeters]
Part Weight per unit (gram): 0.0082

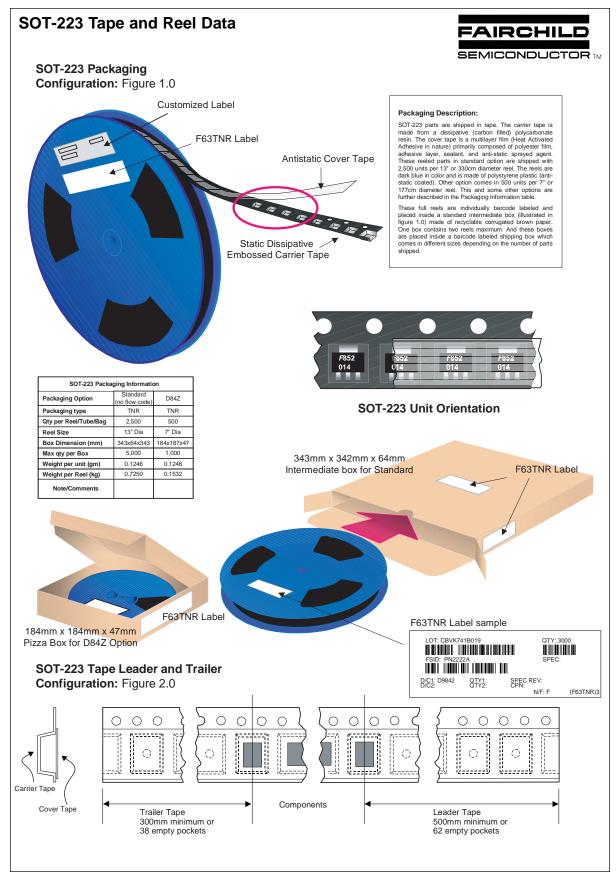


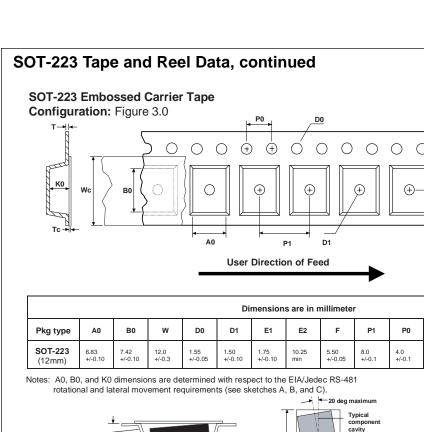


CONTROLLING DIMENSION IS INCH VALUES IN [ ] ARE MILLIMETERS SOT 23, 3 LEADS LOW PROFILE

NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

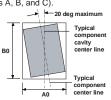






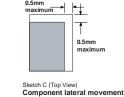


SOT-223 Reel Configuration: Figure 4.0



Sketch B (Top View)

Component Rotation



0.292 +/-0.0130

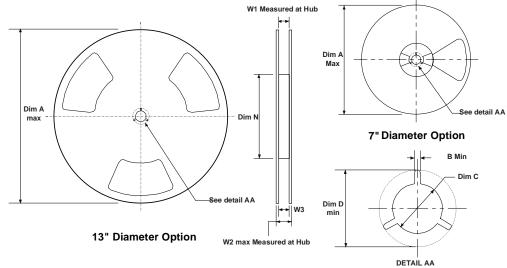
Wc

Tc

0.06 +/-0.02

K0

1.88 +/-0.10

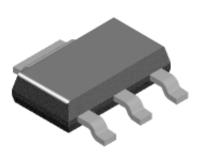


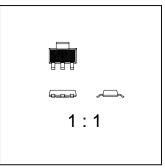
|                                                                              | Dimensions are in inches and millimeters |               |              |                                   |               |                  |                                  |               |                              |  |  |
|------------------------------------------------------------------------------|------------------------------------------|---------------|--------------|-----------------------------------|---------------|------------------|----------------------------------|---------------|------------------------------|--|--|
| Tape Size Reel Option Dim A Dim B Dim C Dim D Dim N Dim W1 Dim W2 Dim W3 (L5 |                                          |               |              |                                   |               | Dim W3 (LSL-USL) |                                  |               |                              |  |  |
| 12mm                                                                         | 7" Dia                                   | 7.00<br>177.8 | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 5.906<br>150     | 0.488 +0.078/-0.000<br>12.4 +2/0 | 0.724<br>18.4 | 0.469 - 0.606<br>11.9 - 15.4 |  |  |
| 12mm                                                                         | 13" Dia                                  | 13.00<br>330  | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 7.00<br>178      | 0.488 +0.078/-0.000<br>12.4 +2/0 | 0.724<br>18.4 | 0.469 - 0.606<br>11.9 - 15.4 |  |  |

#### **SOT-223 Package Dimensions**



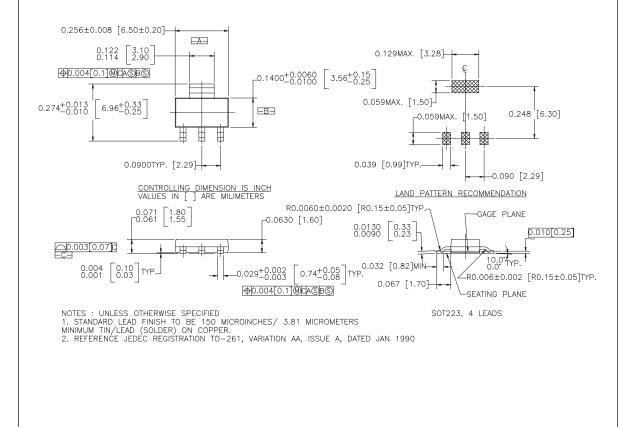
# SOT-223 (FS PKG Code 47)





Scale 1:1 on letter size paper

Part Weight per unit (gram): 0.1246



#### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

 $ACEx^{TM}$ FASTr™ PowerTrench® SyncFET™ Bottomless™ QFET™ TinyLogic™ GlobalOptoisolator™ QSTM UHC™ CoolFET™ GTO™  $VCX^{TM}$  $CROSSVOLT^{\mathsf{TM}}$ QT Optoelectronics™ HiSeC™

DOME™ ISOPLANAR™ Quiet Series™

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

| Datasheet Identification | Product Status            | Definition                                                                                                                                                                                                            |
|--------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Advance Information      | Formative or<br>In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.                                                                                    |
| Preliminary              | First Production          | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |
| No Identification Needed | Full Production           | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.                                                       |
| Obsolete                 | Not In Production         | This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.                                                   |

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and h

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 700 2910

Europe, Middle East and Africa Technical Supp Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative



#### **OUR CERTIFICATE**

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

















Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com